

## High voltage power Schottky rectifier

### Main product characteristics

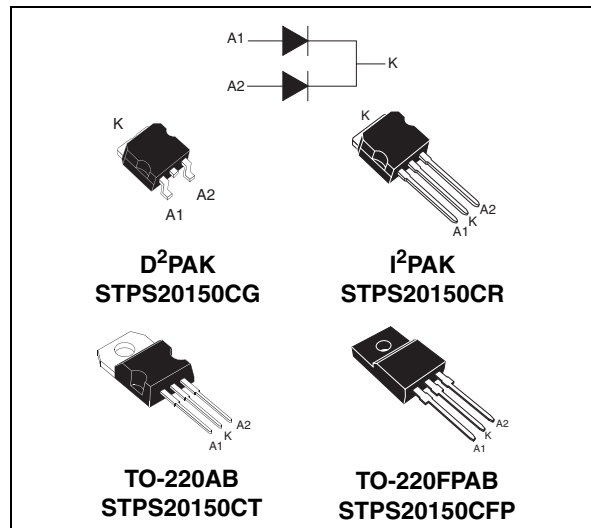
$I_{F(AV)}$	2 x 10 A
$V_{RRM}$	150 V
$T_j$	175° C
$V_F(max)$	0.75 V

### Features and benefits

- High junction temperature capability
- Good trade off between leakage current and forward voltage drop
- Low leakage current
- Avalanche capability specified
- Insulated package
  - TO-220FPAB  
Insulating voltage = 2000 V  
Typical package capacitance 12 pF

### Description

Dual center tap schottky rectifier designed for high frequency Switched Mode Power Supplies.



### Order Codes

Part Number	Marking
STPS20150CT	STPS20150CT
STPS20150CG	STPS20150CG
STPS20150CG-TR	STPS20150CG
STPS20150CR	STPS20150CR
STPS20150CFP	STPS20150CFP

**Table 1. Absolute ratings (limiting values)**

Symbol	Parameter				Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage				150	V
$I_{F(RMS)}$	RMS forward current				30	A
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO-220AB I <sup>2</sup> PAK, D <sup>2</sup> PAK	$T_C = 155^\circ\text{C}$	Per diode	10	A
		TO-220FPAB	$T_C = 135^\circ\text{C}$	Per device	20	
$I_{FSM}$	Surge non repetitive forward current		$t_p = 10\text{ ms sinusoidal}$		180	A
$P_{ARM}$	Repetitive peak avalanche power		$t_p = 1\ \mu\text{s}$ $T_j = 25^\circ\text{C}$		6700	W
$T_{stg}$	Storage temperature range				-65 to + 150	° C
$T_j$	Maximum operating junction temperature <sup>(1)</sup>				175	° C

1.  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  condition to avoid thermal runaway for a diode on its own heatsink

# 1 Characteristics

**Table 2. Thermal resistance**

Symbol	Parameter		Value	Unit	
$R_{th(j-c)}$	Junction to case	TO-220AB, D <sup>2</sup> PAK, I <sup>2</sup> PAK	Per diode	2.2	° C/W
		TO-220FPAB		4.5	
		TO-220AB, D <sup>2</sup> PAK, I <sup>2</sup> PAK	Total	1.3	
		TO-220FPAB		3.5	
$R_{th(c)}$	Coupling	TO-220AB, D <sup>2</sup> PAK, I <sup>2</sup> PAK		0.3	
		TO-220FPAB		2.5	

When the diodes 1 and 2 are used simultaneously:  
 $\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-l)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$

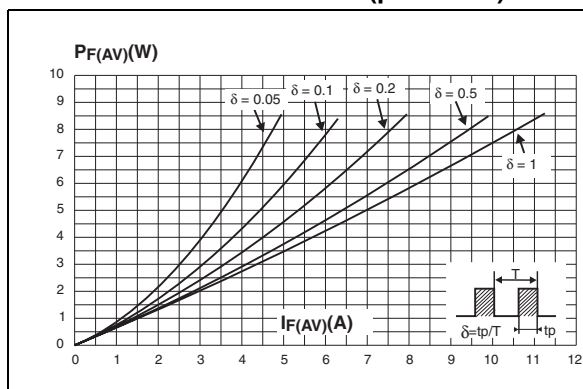
**Table 3. Static electrical characteristics (per diode)**

Symbol	Parameter	Tests conditions		Min.	Typ	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			5.0	$\mu\text{A}$
		$T_j = 125^\circ\text{C}$				5.0	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 10\text{ A}$			0.92	V
		$T_j = 125^\circ\text{C}$			0.69	0.75	
		$T_j = 25^\circ\text{C}$	$I_F = 20\text{ A}$			1	
		$T_j = 125^\circ\text{C}$			0.79	0.86	

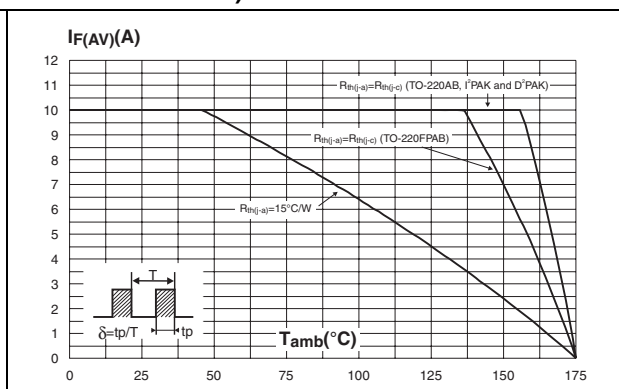
- $t_p = 5\text{ ms}$ ,  $\delta < 2\%$
- $t_p = 380\ \mu\text{s}$ ,  $\delta < 2\%$

To evaluate the conduction losses use the following equation:  
 $P = 0.64 \times I_{F(AV)} + 0.011 I_{F(RMS)}^2$

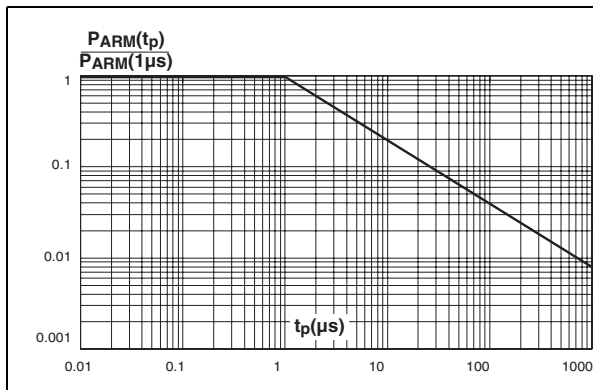
**Figure 1. Average forward power dissipation versus average forward current (per diode)**



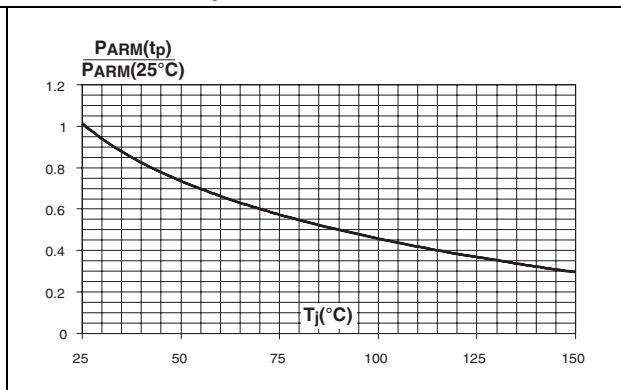
**Figure 2. Average forward current versus ambient temperature (delta = 0.5, per diode)**



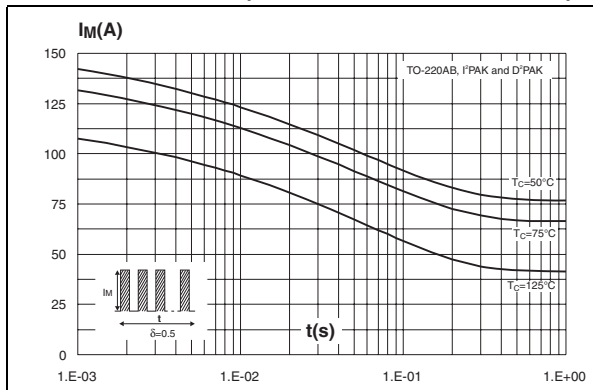
**Figure 3. Normalized avalanche power derating versus pulse duration**



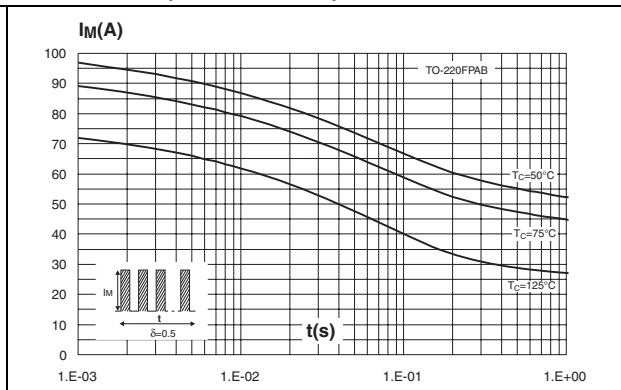
**Figure 4. Normalized avalanche power derating versus junction temperature**



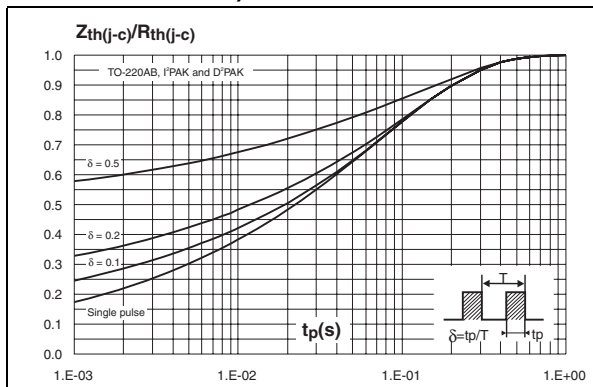
**Figure 5. Non repetitive surge peak forward current versus overload duration - maximum values, per diode (TO-220AB, D<sup>2</sup>PAK, I<sup>2</sup>PAK)**



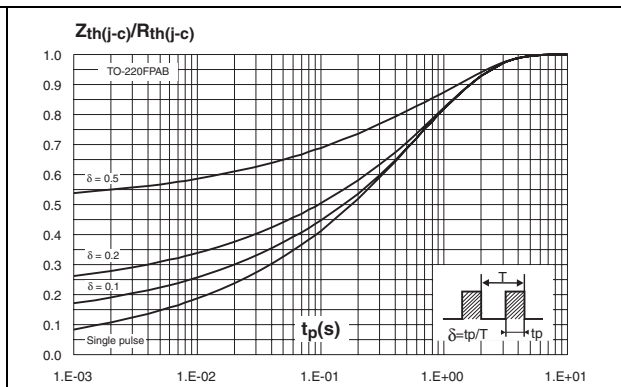
**Figure 6. Non repetitive surge peak forward current versus overload duration - maximum values, per diode (TO-220FPAB)**



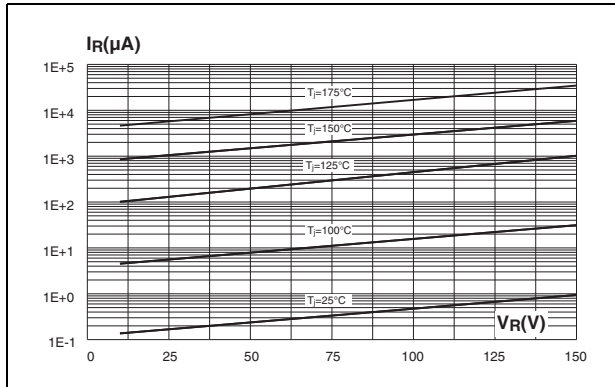
**Figure 7. Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB, D<sup>2</sup>PAK, I<sup>2</sup>PAK)**



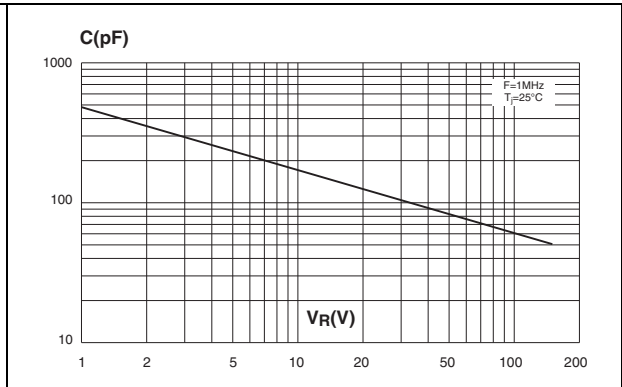
**Figure 8. Relative variation of thermal impedance junction to case versus pulse duration (TO-220FPAB)**



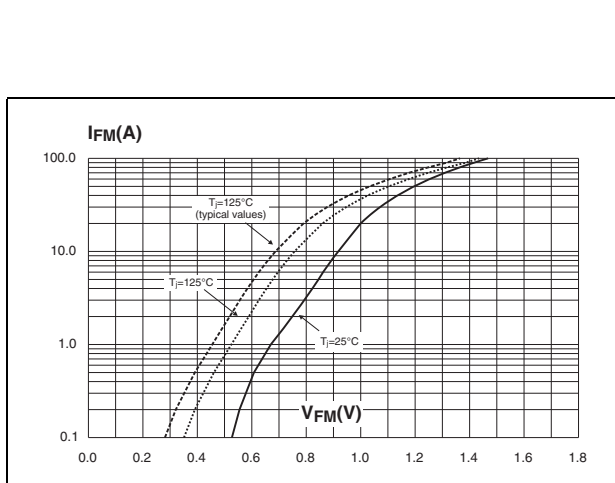
**Figure 9. Reverse leakage current versus reverse voltage applied (typical values, per diode)**



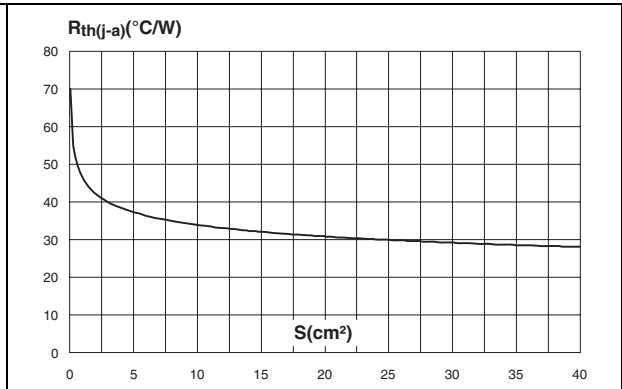
**Figure 10. Junction capacitance versus reverse voltage applied (typical values, per diode)**



**Figure 11. Forward voltage drop versus forward current (per diode)**



**Figure 12. Thermal resistance junction to ambient versus copper surface under tab - Epoxy printed circuit board, copper thickness = 35  $\mu m$  (STPS20150CG only)**



## 2 Package information

Epoxy meets UL94, V0.

**Table 4. D<sup>2</sup>PAK Dimensions**

REF.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

**Figure 13. D<sup>2</sup>PAK footprint dimensions (in mm)**

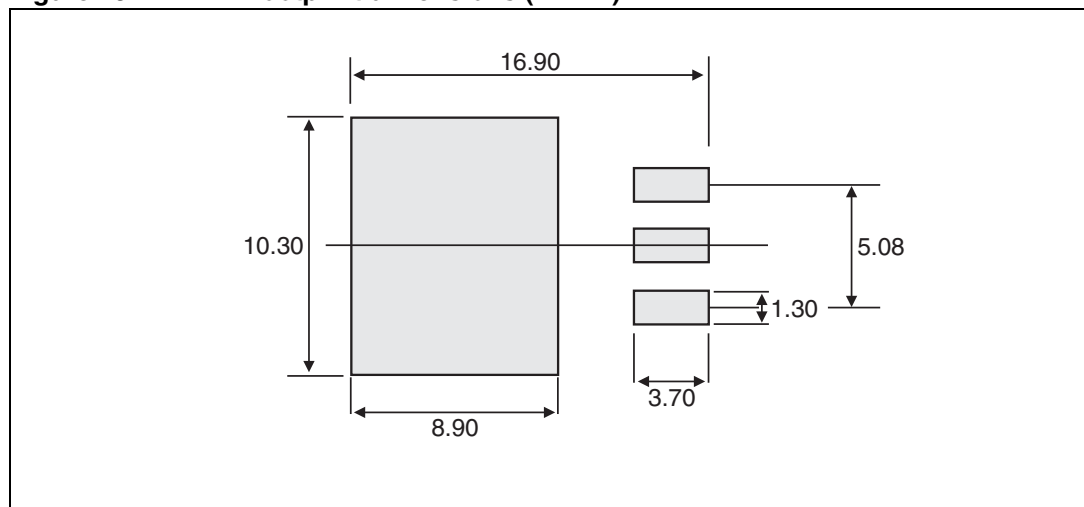
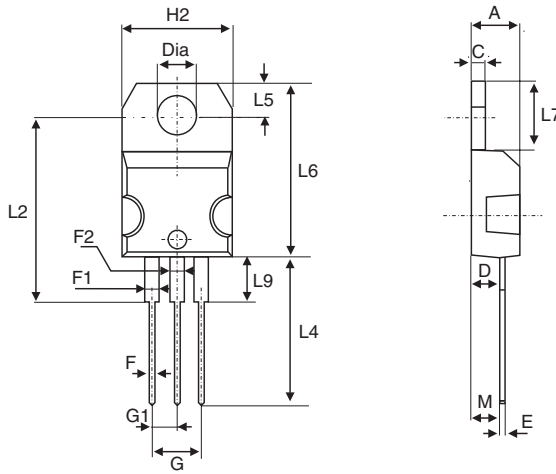
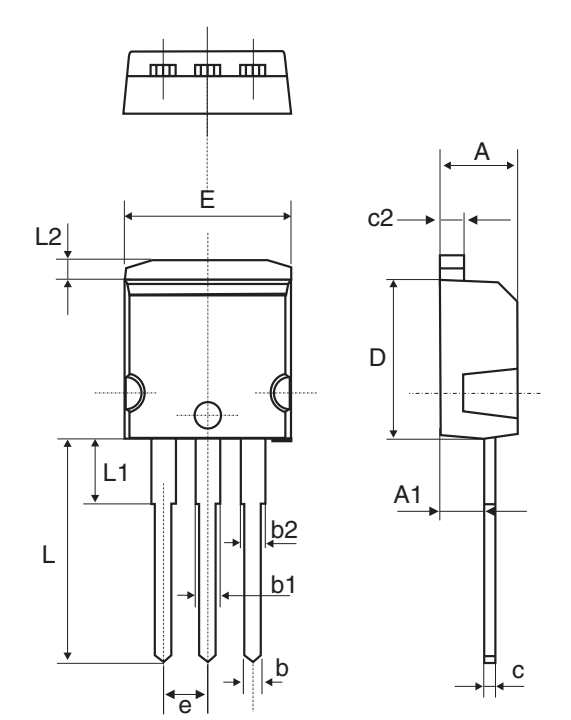


Table 5. TO-220AB Dimensions



REF.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

Table 6. I<sup>2</sup>PAK Dimensions


REF.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.40	2.72	0.094	0.107
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.044	0.067
c	0.49	0.70	0.019	0.028
c2	1.23	1.32	0.048	0.052
D	8.95	9.35	0.352	0.368
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
E	10	10.40	0.394	0.409
L	13	14	0.512	0.551
L1	3.50	3.93	0.138	0.155
L2	1.27	1.40	0.050	0.055

**Table 7. TO-220FPAB Dimensions**

REF.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).



### 3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS20150CT	STPS20150CT	TO-220AB	2.20 g	50	Tube
STPS20150CG	STPS20150CG	D <sup>2</sup> PAK	1.48 g	50	Tube
STPS20150CG-TR	STPS20150CG	D <sup>2</sup> PAK	1.48 g	1000	Tape and reel
STPS20150CR	STPS20150CR	I <sup>2</sup> PAK	1.49 g	50	Tube
STPS20150CFP	STPS20150CFP	TO-220FPAB	2.0 g	50	Tube

### 4 Revision history

Date	Revision	Description of Changes
Jul-2003	6D	Last update.
31-May-2006	7	Reformatted to current standard. Added ECOPACK statement. Changed nF to pF in Figure 10.
07-Mar-2007	8	Reworded footnote to Table 1. Corrected typing error in Table 3.

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